NSN 5962-00-399-4595

Memory Microcircuit - Page 1 of 1



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Body Length: 0.785 inches **Body Width:** Between 0.220 inches and 0.310 inches **Body Height:** Between 0.140 inches and 0.185 inches **Maximum Power Dissipation Rating:** 176.0 milliwatts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Hermetically sealed and monolithic and positive outputs and medium power and medium speed **Inclosure Material:** Ceramic and glass **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Transistor-transistor logic **Input Circuit Pattern:** Dual 4 input **Case Outline Source And Designator:** D-1 mil-m-38510 **Terminal Surface Treatment:** Solder Voltage Rating And Type Per Characteristic: -1.5 volts power source and 5.5 volts power source Memory Device Type: Rom **Test Data Document:** 89954-144a8126 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 14 printed circuit Shelf Life: N/a Unit Of Measure: --**Demilitarization:** Yes - demil/mli Fiig: A458a0